Beam Test Data Analysis

Review of the Bari TKRDigi

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Review approach

We are looking for a semplified version of TKRBariDigiAlg (not excluding the "Full simulation" version)

- Level 0: no SSDs detailed simulation (i.e. No eh propagation, no current signal induced on the strips and no electronic simulation).
- Level 1: re-introduce only the cluster propagation (in order to simulate the sharing effect alone)
- Level 2: re-introduce the signal simulation (current Bari Digi algorithm version)

MC (Simple)Digit simulation: Level 0

- convert the energy deposition Edep in the near strip channel to number of pairs Np=Edep/3.6eV
- add a fluctuation on Np by using a gaussian random number with mean=0 and σ = sqtr(F*Np), where F=0.1 is the Fano factor for Silicon
- add a fluctuation due to electronic noise of 1550 ENC by using a gaussian random number with mean=0 and σ =1550
- convert the Np in charge Q unit (fC), if Np>0, otherwise set Q=0
- convert Q in voltage, by using the electronic gain and taking the saturation into account, i.e. V(mV) = min(Q(fC)*G, 1100), where G=100 mV/fC (a gain fluctution os 6% includeded)
- compare the voltage V with the threshold Vth of 125 mV, assuming that a most probable value of MIP is 500 mV (about 5 fC), then fire the channel strip if V>Vth
- convert Q in T1 and T2 (where ToT = T2-T1) by using parameters from PSPICE simulation
- N.B. The Bari digit needs the L1trigger simulation in order to take into account the Tack (~ 2µs) and Treq (~ 1µs)

Parameters from PSPICE simulation for Q->ToT conversion



MC re-production strategy

- TkrDigi (Bari version) v2r5p1 (BeamtestRelease-v6r0919p1)
- 6GeV protons and 5GeV electrons (0degee) generated by ps_setup (ps_mc.root file as output) and digit, recon, merit and mc output root file produced using Gleam.

Raw ToTs and hits profile plots

6GeV protons (run 1423)





Raw ToTs and hits profile plots

5GeV e- (run 1460)



Raw ToT